NSN 5961-01-361-0124

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-361-0124 **Inclosure Material:** Ceramic **Overall Length:** 0.786 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Terminal **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 0.32 amperes drain current all transistor **Power Rating Per Characteristic:** 3.0 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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